

Interface analysis of Ag/n-type Si contacts in n-type PERT solar cells

Por: [Ferrada, P](#) (Ferrada, Pablo)^[1]; [Rudolph, D](#) (Rudolph, Dominik)^[3]; [Portillo, C](#) (Portillo, Carlos)^[1]; [Adrian, A](#) (Adrian, Adrian)^[3]; [Correa-Puerta, J](#) (Correa-Puerta, Jonathan)^[2]; [Sierpe, R](#) (Sierpe, Rodrigo)^[4]; [del Campo, V](#) (del Campo, Valeria)^[2]; [Flores, M](#) (Flores, Marcos)^[6]; [Corrales, TP](#) (Corrales, Tomas P.)^[2]; [Henriquez, R](#) (Henriquez, Ricardo)^[2] [...Más](#)

[Ver número de ResearchID y ORCID de Web of Science](#)

PROGRESS IN PHOTOVOLTAICS

Volumen: 28

Número: 5

Páginas: 358-371

DOI: 10.1002/pip.3242

Fecha de publicación: MAY 2020

Acceso anticipado: FEB 2020

Tipo de documento: Article

[Ver impacto de la revista](#)

Abstract

To increase efficiencies of bifacial solar cells, emitter, back surface field (BSF), and metal patterns must be optimized. We study the influence of paste volume, through multiple prints, of two silver pastes on the contact formation at the rear side of n-type passivated emitter and rear totally diffused (n-PERT) solar cells with two BSF doping profiles. Differences in fingers' electrical properties were found between pastes. Contact resistivity shows a relative difference of 27.6%, partially explained by changes in the silver crystallites formation at the Ag/Si interface and in the crystallites' penetration depth. Variations in crystallites formation and penetration between pastes can reach 38.4% and 48.8%, respectively. Line resistance shows a difference between pastes, appearing as the main cause of an absolute efficiency difference of 2.9%. Fingers' structural and electrical properties are modified by increasing the paste volume. Microstructure analysis reveals that additional metallic printing does not only increase line cross sectional area but also increases the formation of silver crystallites, which can reach a relative increment of 23.9% between first and second prints. Further printing does not necessarily decrease contact resistivity, but reduces line resistance in up to 94.9%, which results in an absolute efficiency increase of 2.2%. In addition, the higher presence of silver oxide in the finger is related to a higher efficiency in the formation of silver crystallites. Finally, BSF doping has an influence in the open circuit voltage, short circuit current density, and contact resistivity, with differences that can reach 8.7 mV, 0.2 mA/cm², and 6.1 mΩ cm², respectively, depending on paste and number of prints.

Palabras clave

Palabras clave de autor:[AFM](#); [FE-SEM](#); [metallization](#); [solar cells](#); [XPS](#)

KeyWords Plus:[THICK-FILM CONTACTS](#); [SILVER](#); [PASTE](#); [RESISTANCE](#)

Información del autor

Dirección para petición de copias: Ferrada, P (autor para petición de copias)

Univ Antofagasta, Ctr Desarrollo Energet Antofagasta, Angamos 0601, Antofagasta 1270300, Chile.

Direcciones:

[1] Univ Antofagasta, Ctr Desarrollo Energet Antofagasta, Angamos 0601, Antofagasta 1270300, Chile

[2] Univ Tecn Federico Santa Maria, Dept Fis, Valparaiso, Chile

[3] Int Solar Energy Res Ctr Konstanz ISC, Adv Cell Concepts, Constance, Germany

[4] Univ Chile, Dept Quim Farmacol & Toxicol, Santiago, Chile

[5] Adv Ctr Chron Dis, Santiago, Chile

[6] Univ Chile, Dept Fis, FCFM, Santiago, Chile

Direcciones de correo electrónico:pablo.ferrada@uantof.cl

Financiación

Entidad financiadora Mostrar más información	Número de concesión
Bundesministerium fur Wirtschaft und Energie (BMWi)	FKZ 0324206
European Solar-Era-Net	038
Comision Nacional de Investigacion Cientifica y Tecnologica (CONICYT-FONDAP program)	15110019 15130011
Comision Nacional de Investigacion Cientifica y Tecnologica (CONICYT) CONICYT FONDECYT	11160664 11190239 11190289
Fondo de Equipamiento Cientifico y Tecnologico (FONDEQUIP)	EQM170111
Corporacion de Fomento de la Produccion (CORFO)	17PTECES-75830
Ministerio de Educacion de Chile (MINEDUC)	UA ANT 1755
USM	Pi-L-18-21
Millennium Nucleus MULTIMAT-ICM/MINECON	

[Ver texto de financiación](#)

Editorial

WILEY, 111 RIVER ST, HOBOKEN 07030-5774, NJ USA

Información de la revista

- **Impact Factor:** [Journal Citation Reports](#)

Categorías / Clasificación

Áreas de investigación:Energy & Fuels; Materials Science; Physics

Categorías de Web of Science:Energy & Fuels; Materials Science, Multidisciplinary; Physics, Applied

Información del documento

Idioma:English

Número de acceso: WOS:000510603100001

ISSN: 1062-7995

eISSN: 1099-159X